

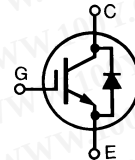
High Speed IGBT with Diode

IXSH 30 N60CD1
 IXSK 30 N60CD1
 IXST 30 N60CD1

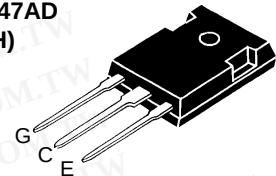
$$\begin{aligned} V_{CES} &= 600 \text{ V} \\ I_{C25} &= 55 \text{ A} \\ V_{CE(sat)} &= 2.5 \text{ V} \\ t_{fi} &= 70 \text{ ns} \end{aligned}$$

Short Circuit SOA Capability

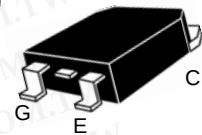
Preliminary data



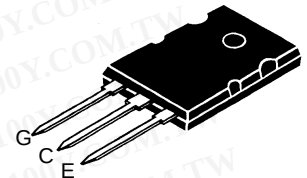
TO-247AD
(IXSH)



TO-268 (D3)
(IXST)



TO-264
(IXSK)



G = Gate C = Collector
 E = Emitter TAB = Collector

Features

- International standard packages: JEDEC TO-247, TO-264& TO-268
- Short Circuit SOA capability
- High frequency IGBT and anti-parallel FRED in one package
- New generation HDMOS™ process

Applications

- AC motor speed control
- DC servo and robot drives
- DC choppers
- Uninterruptible power supplies (UPS)
- Switch-mode and resonant-mode power supplies

Advantages

- Space savings (two devices in one package)
- Easy to mount with 1 screw (isolated mounting screw hole)
- Surface mountable, high power case style
- Reduces assembly time and cost
- High power density

Symbol	Test Conditions	Maximum Ratings	
V_{CES}	$T_J = 25^\circ\text{C to } 150^\circ\text{C}$	600	V
V_{CGR}	$T_J = 25^\circ\text{C to } 150^\circ\text{C}; R_{GE} = 1 \text{ M}\Omega$	600	V
V_{GES}	Continuous	± 20	V
V_{GEM}	Transient	± 30	V
I_{C25}	$T_C = 25^\circ\text{C}$	55	A
I_{C90}	$T_C = 90^\circ\text{C}$	30	A
I_{CM}	$T_C = 25^\circ\text{C}, 1 \text{ ms}$	110	A
SSOA (RBSOA)	$V_{GE} = 15 \text{ V}, T_J = 125^\circ\text{C}, R_G = 10 \Omega$ Clamped inductive load, $V_{CL} = 0.8 V_{CES}$	$I_{CM} = 60$	A
t_{SC} (SCSOA)	$V_{GE} = 15 \text{ V}, V_{CE} = 360 \text{ V}, T_J = 125^\circ\text{C}$ $R_G = 33 \Omega$, non repetitive	10	μs
P_C	$T_C = 25^\circ\text{C}$	200	W
T_J		-55 ... +150	$^\circ\text{C}$
T_{JM}		150	$^\circ\text{C}$
T_{stg}		-55 ... +150	$^\circ\text{C}$
M_d	Mounting torque	1.13/10	Nm/lb.in.
Weight		6	g
Maximum lead temperature for soldering 1.6 mm (0.062 in.) from case for 10 s		300	$^\circ\text{C}$

Symbol	Test Conditions	Characteristic Values ($T_J = 25^\circ\text{C}$, unless otherwise specified)		
		min.	typ.	max.
BV_{CES}	$I_C = 750 \mu\text{A}, V_{GE} = 0 \text{ V}$	600		V
$V_{GE(th)}$	$I_C = 2.5 \text{ mA}, V_{CE} = V_{GE}$	4		7 V
I_{CES}	$V_{CE} = 0.8 \cdot V_{CES}$ $V_{GE} = 0 \text{ V}$			$T_J = 25^\circ\text{C}$ 200 μA $T_J = 125^\circ\text{C}$ 3 mA
I_{GES}	$V_{CE} = 0 \text{ V}, V_{GE} = \pm 20 \text{ V}$			$\pm 100 \text{ nA}$
$V_{CE(sat)}$	$V_{GE} = 15 \text{ V}$			$I_C = I_{C90}$ 2.5 V

Symbol	Test Conditions	Characteristic Values		
		(T _j = 25°C, unless otherwise specified)		
		min.	typ.	max.
g_{fs}	I _C = I _{C90} ; V _{CE} = 10 V, Pulse test, t ≤ 300 μs, duty cycle ≤ 2 %	10		S
C_{ies}	V _{CE} = 25 V, V _{GE} = 0 V, f = 1 MHz		3100	pF
C_{oes}			240	pF
C_{res}			50	pF
Q_g	I _C = I _{C90} ; V _{GE} = 15 V, V _{CE} = 0.5 V _{CES}		100	nC
Q_{ge}			30	nC
Q_{gc}			38	nC
t_{d(on)}	Inductive load, T_j = 25°C		30	ns
t_{ri}	I _C = I _{C90} ; V _{GE} = 15 V		30	ns
t_{d(off)}	V _{CE} = 0.8 V _{CES} ; R _G = 4.7 Ω		90	150 ns
t_{fi}			70	120 ns
E_{off}	Note 1.		0.7	1.2 mJ
t_{d(on)}	Inductive load, T_j = 125°C		35	ns
t_{ri}			35	ns
E_{on}	I _C = I _{C90} ; V _{GE} = 15 V		0.5	mJ
t_{d(off)}	V _{CE} = 0.8 V _{CES} ; R _G = 4.7 Ω		150	ns
t_{fi}			140	ns
E_{off}	Note 1		1.2	mJ
R_{thJC}	TO-247 TO-264			0.62 K/W
R_{thCK}			0.25	K/W
R_{thCK}			0.15	K/W

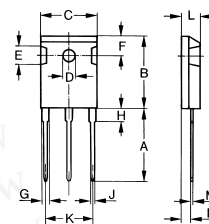
Reverse Diode (FRED)		Characteristic Values (T _J = 25°C, unless otherwise specified)		
Symbol	Test Conditions	min.	typ.	max.
V _F	I _F = I _{C90°} ; V _{GE} = 0 V Note 2			1.7 V 2.5 V
I _{RM}	I _F = 100 A; V _{GE} = 0 V; T _J = 100°C V _R = 100 V; -di _F /dt = 100 A/μs		2	2.5 A
t _{rr}	I _F = 1 A; -di/dt = 100 A/μs; V _R = 30 V T _J = 25°C		35	50 ns
R _{thJC}				1.0 K/W

Notes: 1. Switching times may increase for V_{CE} (Clamp) $> 0.8 \cdot V_{CES}$, higher T_J or increased R_G
2. Pulse test. $t \leq 300 \mu s$, duty cycle $d \leq 2\%$

TO-268AA (IXST) (D³ PAK)

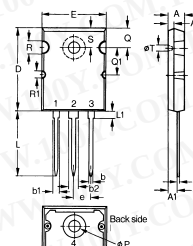
Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	4.9	5.1	.193	.201
A ₁	2.7	2.9	.106	.114
A ₂	.02	.25	.001	.010
b	1.15	1.45	.045	.057
b ₂	1.9	2.1	.75	.83
C	.4	.65	.016	.026
D	13.80	14.00	.543	.551
E	15.85	16.05	.624	.632
E ₁	13.3	13.6	.524	.535
e	5.45 BSC		.215 BSC	
H	18.70	19.10	.736	.752
L	2.40	2.70	.094	.106
L1	1.20	1.40	.047	.055
L2	1.00	1.15	.039	.045
L3	0.25 BSC		.010 BSC	
L4	3.80	4.10	.150	.161

TO-247 AD (IXSH) Outline



Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	19.81	20.32	0.780	0.800
B	20.80	21.46	0.819	0.845
C	15.75	16.26	0.610	0.640
D	3.55	3.65	0.140	0.144
E	4.32	5.49	0.170	0.216
F	5.4	6.2	0.212	0.244
G	1.65	2.13	0.065	0.084
H	-	4.5	-	0.177
J	1.0	1.4	0.040	0.055
K	10.8	11.0	0.426	0.433
L	4.7	5.3	0.185	0.209
M	0.4	0.8	0.016	0.031
N	1.5	2.49	0.087	0.102

TO-264 AA (IXSK) Outline



Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	4.82	5.13	.190	.202
A1	2.54	2.89	.100	.114
A2	2.00	2.10	.079	.083
b1	1.12	1.42	.044	.056
b2	2.39	2.69	.094	.106
b2	2.90	3.09	.114	.122
c	0.53	0.83	.021	.033
D	25.91	26.16	1.020	1.030
E	19.81	19.96	.780	.786
e	5.46	BSC	.215	BSC
J	0.00	0.25	.000	.010
K	0.00	0.25	.000	.010
L	20.32	20.83	.800	.820
L1	2.29	2.59	.090	.102
P	3.17	3.66	.125	.144
Q	6.07	6.27	.239	.247
Q1	8.38	8.69	.330	.342
R	3.81	4.32	.150	.170
R1	1.78	2.29	.070	.090
S	6.04	6.30	.238	.248
T	1.57	1.83	.062	.072

Min. Recommended Footprint

